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U.S. PTO
042004

HIGH DENSITY MULTI-LAYER MICROCOIL AND METHOD FOR FABRICATING THE SAME

BACKGROUND OF THE INVENTION

Field of the Invention

5 The invention generally relates to a microcoil and a fabrication process of the microcoil, and particularly relates to a high density multi-layer microcoil and a method for fabricating high density multi-layer microcoil.

Related Art

The market size of microcoils has become larger and larger. According to
10 conservative market estimate of Nexus, there is a 100 million USD market on basic needs
for microcoils, and hard to be estimated if including needs for further applications. The
microcoils are so small that conventional coil-winding method has limitation for increasing
the density. Now, by applying techniques of MEMS (micro-electro-mechanical-system),
the coil size can be in a range of 0.01 to 1 inch. The MEMS is trend of microcoil
15 development.

However, the MEMS generally utilize semi-conductor fabrication processes, which
are basically for planar constructions. Therefore, a conventional microcoil is generally of a
planar construction that is made by multi-layer depositions of metal and insulation layers,
and through photolithography processes.

20 There have been successful cases of microcoil fabrications through MEMS. For
example, as shown in FIG. 1, US Patent No. 5,852,866, a microcoil includes two stacked
coil windings 1a, 1b formed in parallel on a substrate and connected with a through-plating
2; a magnetic core 5 enclosed by a top part 6, a bottom part 8, a surrounding magnetic core
area 7 and an insulator 4. Ends of the coil windings 1a, 1b are linked to contact points 3
25 for use. However, the aforesaid microcoil is a planar construction in which the coil is

perpendicular to the substrate that will induce current on the substrate (especially silicon substrate) and waste energy and lower the quality. Therefore, this microcoil is not applicable for high frequency circuits. Moreover, since the axis of the coil winding is perpendicular to the plane of substrate, the coil is hard to be extended in the axial direction.

- 5 Therefore, it is limited for the number of winding, or the process for multi-layer will be very complicated.

Therefore, this is a requirement for us to acquire a microcoil construction that is parallel to the substrate to avoid current induction, and suitable for high frequency circuit applications.

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SUMMARY OF THE INVENTION

The object of the invention is to provide a high density multi-layer microcoil and a method for fabricating high density multi-layer microcoil. The coil winding is perpendicular to the substrate so that the magnetic field is parallel to the substrate and will not generate induction current on the substrate.

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A high density multi-layer microcoil according to the invention includes a substrate, a multi-layer coil winding and a magnetic core. The multi-layer coil winding is composed of a plurality of coil element layers linking one another. Each coil element is further composed of N windings in a plane. Two ends of the coil layers are contact points for outer circuits. The coil elements are perpendicular to the substrate. The whole construction is supported by a dry film photoresist. The coil elements are made of conductive material with low melting point. The photoresist is chosen from high strength materials.

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In the fabrication process, the times of optical exposure are determined by the winding number of each coil element. For a coil element with N windings, the windings are numbered as 1 to N from the inner to the outer. Each coil winding is composed of a top parallel portion, a bottom parallel portion and two vertical portions and formed as a planar coil element perpendicular to the substrate. The photoresist structure for supporting the multi-layer coil winding is made by $4N+1$ times of deposition. The steps are:

- a) In 1 to 2N depositions of photoresist material, using photolithography process to form the lower half portions of the 1 to N windings of the coil elements. The lower haft portions include the bottom parallel portions and lower halves of vertical portions;
- b) In 2N+1 to 4N depositions of photoresist material, using photolithography process to form the upper half portions of the N to 1 windings of the coil elements. The upper haft portions include upper halves of vertical portions and the top parallel portions; and
- c) In the last (4N+1) deposition, using photolithography process to form a top of the photoresist structure.

Between the step a) and step b), a magnetic core can be made between the lower and 10 the upper portions if needed. In practice, the process is designed for fewest steps. In the first planning stage, the number of layers, the number of windings for each coil element, the left or right-hand direction of coil winding, and top or bottom position of the starting point are all to be considered.

BRIEF DESCRIPTION OF THE DRAWINGS

15 The invention will become more fully understood from the detailed description given hereinbelow. However, this description is for purposes of illustration only, and thus is not limitative of the invention, wherein:

FIG. 1 is a constructional view of a microcoil of prior arts;

FIG. 2 is a constructional view of a microcoil of the invention;

20 FIG. 3A is a sectional plane view of an embodiment of a microcoil according to the invention;

FIG. 3B is a sectional side view of an embodiment of a microcoil according to the invention; and

FIGS. 4A to 4V are sequential sectional views corresponding to fabrication steps of

process for making a microcoil of FIG. 3B.

DETAILED DESCRIPTION OF THE INVENTION

As shown in FIG. 2, a high density multi-layer microcoil according to the invention includes a substrate 10, a multi-layer coil winding 60, a magnetic core 70 and an photoresist structure 80. The multi-layer coil winding 60 is composed of a plurality of coil element layers, e.g., C1, C2, C3 and C4, linking one another. Each coil element C1, C2, C3 or C4 is further composed of N windings in a plane. Two ends 61, 62 of the coil layers C1, C4 are contact points for outer circuits. The coil elements C1, C2, C3, C4 are perpendicular to the substrate 10 and linked sequentially to form the continuous coil winding 60. Because the coil winding 60 is perpendicular to the substrate 10, the magnetic field is parallel to the substrate and will not generate induction current to the substrate as prior arts do.

Because the coil winding 60 and the magnetic core 70 are all suspended from the substrate 10, they have to be supported by a suitable structure. The invention uses a dry film of photoresist 80 for this purpose. The photoresist structure 80 encloses the coil winding 60 and the magnetic core 70. The structure 80 provides a tunnel to hold the coil winding 60 and two openings for the end points 61, 62 to come out. The photoresist structure 80 also supports the magnetic core 70 in the axis of the coil winding 60 for increasing inductance of the coil winding 60. If a higher inductance is not necessary, then the magnetic core 70 can be omitted, and the structure is simpler.

Since the high density multi-layer microcoil of the invention is a tridimensional structure, the fabrication process has to be specially designed in order to utilize general planar fabrication process. An applicable method is first to form a dry film of photoresist structure 80 with coil tunnel. Then, removing the photoresist from the tunnel by a photo-developing process and forming an empty tunnel. Finally, injecting a conductive material with low melting point into the tunnel and forming the coil winding 60. The magnetic core 70 is also formed during the process of forming the photoresist structure 80. As shown in FIG. 2, since the magnetic core 70 locates in the axis (central line) of the coil winding 60, it

can be made when a half of the photoresist structure 80 is finished. While, if the magnetic core 70 is not needed, the process for the magnetic core 70 can be omitted.

Before starting the fabrication process, the number of layers of the coil winding 60 and the number of windings of each coil element have to be planned. As shown in FIGS. 5 3A and 3B, an example of a multi-layer microcoil is made with 7 layers in which each coil element layer is formed with two windings. Some dimensions are also illustrated for reference. The constructional process for the photoresist structure 80 will be more complicated if more windings are needed. The process is first to form the lower half portion of the photoresist structure 80 that includes a lower half tunnel of the multi-layer 10 microcoil 60. Secondly, placing the magnetic core 70. Thirdly, forming the upper half portion of the photoresist structure 80 that includes an upper half tunnel of the multi-layer microcoil 60. The links among the coil element layers is made on the upper half portion of the photoresist structure 80, as shown in FIG. 2, or on the lower upper half portion of the photoresist structure 80 if suitable. Through the aforesaid process, a continuos tunnel for 15 the multi-layer microcoil 60 and a magnetic core 70 in the axis of the coil winding are made. When the magnetic core 70 is not needed, a process for the core is then omitted.

In the process, the photoresist is chosen from high strength materials, such as SU-8, which is a negative photoresist capable of forming a thick film. The pressure strength of SU-8 is around 60 thousand pounds per square inch and suitable for enduring high-pressure 20 injection of coil material. The coil material is chosen from conductive alloys with low melting point of lead and tin. The material for the magnetic core is chosen from high magnetic permeability materials, such as supermalloy, which is composed of 79% nickel, 15% iron, 5% molybdenum and 0.5% manganese; high magnetic permeability alloy (78.5% nickel and 21.5% iron); iron and cobalt alloy, pure (99.96%) iron or silicon steel.

25 An embodiment of the fabrication process will be described below with reference to FIGS. 4A to 4V, which are sequential drawings corresponding to the steps for making a microcoil of FIG. 3B.

The fabrication process mainly includes steps of forming the lower half portion of photoresist structure, forming the magnetic core and forming the upper half portion of photoresist structure.

The process steps of forming the lower half portion of photoresist structure are
5 illustrated in FIGS. 4A to 4G. In FIG. 4A, a photoresist layer 12 is first deposited on the substrate 10. Then, in FIG. 4B, forming a dry film photoresist 12' by photolithography process. In FIG. 4C, further depositing a photoresist layer 14. And, in FIG. 4D, forming a dry film photoresist 14' by photolithography process. Again, in FIG. 4E, depositing a photoresist layer 16, and in FIG. 4F, forming a dry film photoresist 16'. And finally, in
10 FIG. 4G, depositing a photoresist layer 18, and forming a dry film photoresist 18'. Thus, the lower half dry film photoresist structure is finished. The tunnel for the coil winding is still filled with original photoresist material.

Now, for the steps of forming magnetic core, an insulation layer 20 is first deposited as shown in FIG. 4H. Then, in FIG. 4I, depositing a photoresist layer 22, and forming a dry
15 film photoresist and leaving a space for the magnetic core. Then, in FIG. 4J, etching and removing a portion of the insulation layer 20, and generating an opening 24 under the space for the magnetic core. In FIG. 4K, depositing a layer 26 of high magnetic permeability material. Then, in FIG. 4L, removing excessive high magnetic permeability material besides the magnetic core, and finally, in FIG. 4M, removing the insulation layer 20 and
20 finishing the magnetic core 28. The material of the insulation layer 20 is chosen from silicon dioxide (SiO_2) or silicon nitride (Si_3N_4).

The process steps of forming the upper half portion of photoresist structure are illustrated in FIGS. 4N to 4V. In FIG. 4N, a photoresist layer 30 is first deposited on the substrate 10. Then, in FIG. 4O, forming a dry film photoresist 30' by photolithography process. In FIG. 4P, further depositing a photoresist layer 34 and forming a dry film photoresist 34'. Again, in FIG. 4Q, depositing a photoresist layer 36 and forming a dry film photoresist 36'. Further, in FIG. 4R, depositing a photoresist layer 38 and forming a dry film photoresist 38'. In FIG. 4S, depositing a photoresist layer 40 and forming a dry

film photoresist 40'. And finally, in FIG. 4T, depositing a photoresist layer and forming a top dry film photoresist. Thus, the whole dry film photoresist structure is finished. The tunnel for the coil winding is filled with original photoresist material.

Also, during some steps of forming the portions of the coil winding, each inner end of
5 a coil element has to link with an outer end of an adjacent coil element. The connection tunnels are formed synchronously during the aforesaid steps.

After forming the whole tunnel is finished, the photoresist material in the is removed.
As shown in FIG. 4U, the tunnel for the coil winding is cleared. To clear the tunnel, some
developing liquid is injected through the openings, i.e., the end points 61, 62 of the coil
10 winding as shown in FIG. 2. The process is slow. After the tunnel is cleared, a conductive
alloy with low melting point is injected into the tunnel to form the coil winding, as shown
in FIG. 4V.

A summary of the fabrication process can be made from the aforesaid example of
FIGS. 4A to 4V. For a coil element with N windings, the windings are numbered as 1 to N
15 from inner to outer. Each coil winding is composed of a top parallel portion, a bottom
parallel portion and two vertical portions and formed as a planar coil element perpendicular
to the substrate. The photoresist structure for supporting the multi-layer coil winding is
made by $4N+1$ times of deposition. The steps are:

- a) In 1 to $2N$ depositions of photoresist material, using photolithography process to form
20 the lower half portions of the 1 to N windings of the coil elements. The lower haft portions
include the bottom parallel portions and lower halves of vertical portions;
- b) In $2N+1$ to $4N$ depositions of photoresist material, using photolithography process to
form the upper half portions of the N to 1 windings of the coil elements. The upper haft
portions include upper halves of vertical portions and the top parallel portions; and
- 25 c) In the last ($4N+1$) deposition, using photolithography process to form a top of the
photoresist structure.

During aforesaid steps a) and b), some steps for making a magnetic core can be added. However, if the magnetic core is not needed, the steps are then omitted.

In practice, the process is designed for fewest steps. In the first planning stage, the number of layers, the number of windings for each coil element, the left or right-hand 5 direction of coil winding, and top or bottom position of the starting point are all to be considered.

With the process of the invention, a high density multi-layer microcoil can be obtained. The number of coil winding is determined by multiplication of the layers of the coil and the windings in each coil element, which is therefore not limited in contrast to 10 prior arts. Further, the fabrication process can be carried out just by conventional photolithography and etching process.

The invention being thus described, it will be obvious that the same may be varied in many ways. Such variations are not to be regarded as a departure from the spirit and scope of the invention, and all such modifications as would be obvious to one skilled in the art are 15 intended to be included within the scope of the following claims.